# 2.5V Drive Nch+Nch MOS FET UM6K1N

# Structure

Silicon N-channel MOS FET

# Features

- 1) Two 2SK3018 transistors in a single UMT package.
- 2) The MOS FET elements are independent, eliminating mutual interference.
- 3) Mounting cost and area can be cut in half.
- 4) Low On-resistance.
- 5) Low voltage drive (2.5V drive) makes this device ideal for portable equipment.

### Applications

Interfacing, switching (30V, 100mA)

# Packaging specifications

Туре	Package	Taping
	Code	TN
	Basic ordering unit (pieces)	3000
UM6K1N		0

### •Absolute maximum ratings (Ta=25°C)

<It is the same ratings for Tr1 and Tr2.>

Parameter		Symbol	Limits	Unit
Drain-source voltage		VDSS	30	V
Gate-source voltage		Vgss	±20	V
Droin eurrent	Continuous	ID	±100	mA
Drain current	Pulsed	I <sub>DP</sub> *1	±400	mA
Total power dissipation		P <sub>D</sub> *2	150	mW
Channel temperature		Tch	150	°C
Range of storage temperature		Tstg	-55 to +150	°C

∗1 Pw≤10μs, Duty cycle≤1%

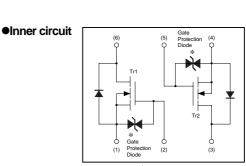
\*2 With each pin mounted on the recommended lands.

# Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a)*	833	°C / W / TOTAL
		1042	°C / W / ELEMENT

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\* With each pin mounted on the recommended lands.



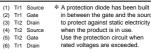
•External dimensions (Unit : mm)

HHH

0.2

Abbreviated symbol : K1

UMT6



Each lead has same dimensions

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# Transistors

# •Electrical characteristics (Ta=25°C)

<It is the same characteristics for Tr1 and Tr2.>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	lgss	-	-	±1	μA	Vgs=±20V, Vps=0V
Drain-source breakdown voltage	V(BR)DSS	30	-	-	V	ID= 10μA, Vgs=0V
Zero gate voltage drain current	IDSS	-	-	1.0	μA	VDS= 30V, VGS=0V
Gate threshold voltage	V <sub>GS (th)</sub>	0.8	-	1.5	V	V <sub>DS</sub> = 3V, I <sub>D</sub> = 100µA
Static drain-source on-state resistance	Dest	-	5	8	Ω	I <sub>D</sub> = 10mA, V <sub>GS</sub> = 4V
	RDS (on)	-	7	13	Ω	I <sub>D</sub> = 1mA, V <sub>GS</sub> = 2.5V
Forward transfer admittance	Y <sub>fs</sub>	20	-	-	mS	I <sub>D</sub> = 10mA, V <sub>DS</sub> = 3V
Input capacitance	Ciss	-	13	-	pF	V <sub>DS</sub> = 5V
Output capacitance	Coss	-	9	_	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	Crss	-	4	-	pF	f=1MHz
Turn-on delay time	t <sub>d (on)</sub>	-	15	-	ns	Vdd≒5V
Rise time	tr	_	35	_	ns	ID= 10mA Vgs= 5V
Turn-off delay time	td (off)	-	80	_	ns	$V_{GS} = 5V$ $R_{L} = 500\Omega$
Fall time	t <sub>f</sub>	_	80	-	ns	R <sub>G</sub> =10Ω

### Electrical characteristic curves

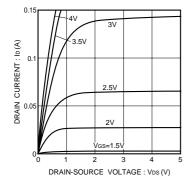


Fig.1 Typical Output Characteristics

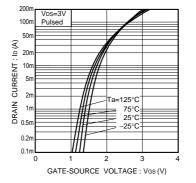


Fig.2 Typical Transfer Characteristics

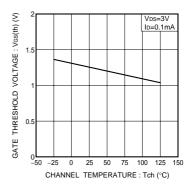


Fig.3 Gate Threshold Voltage vs. Channel Temperature

Ta=25°C Pulsed

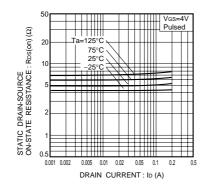
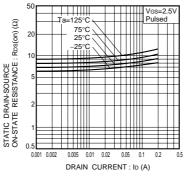
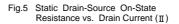


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current (I)





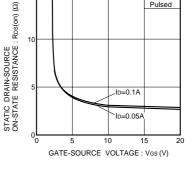


Fig.6 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

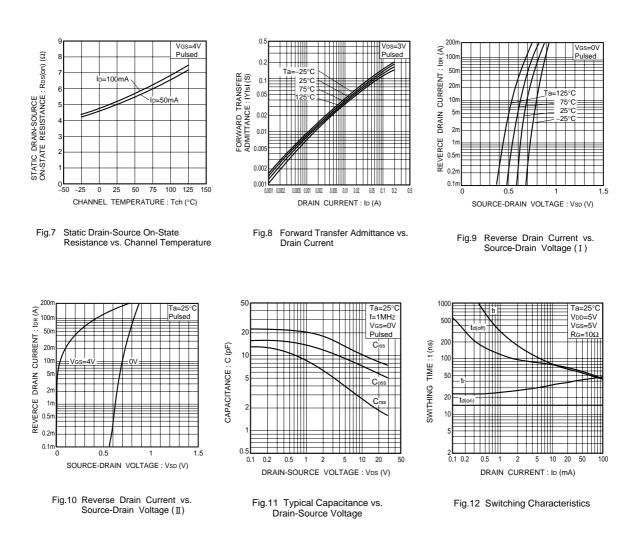
Rev.B

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# Transistors



# •Switching characteristics measurement circuit

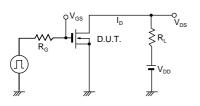


Fig.13 Switching Time Test Circuit

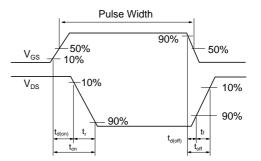


Fig.14 Switching Time Waveforms

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